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APPLICATION NO.	FILING DATE	FIF	RST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/517,589	03/03/2000		Masami Hatori	Q56793	5455	
7590 05/24/2004		, · · · · · · · · · · · · · · · · · · ·	EXAMINER			
Sughrue Mion Zinn Macpeak & Seas PLLC 2100 Pennsylvania Avenue N W			4	RODRIGUEZ,	RODRIGUEZ, ARMANDO	
Washington, DC 20037				ART UNIT	PAPER NUMBER	
			×.	2828		
			Y.	DATE MAILED: 05/24/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

<u> </u>	the state of the s	Application No.	Applicant(s)			
		09/517,589	HATORI ET AL.			
Office Action Summary		Examin r	Art Unit			
		Armando Rodriguez	2828	8		
The MA Period for Reply	ILING DATE of this communication app	pears on the cover sheet with the c	correspondence address	5		
A SHORTENE THE MAILING - Extensions of time after SIX (6) MON - If the period for re; - If NO period for re; - Failure to reply wit Any reply received earned patent term	D STATUTORY PERIOD FOR REPLY DATE OF THIS COMMUNICATION. The period of the provisions of 37 CFR 1.1. THS from the mailing date of this communication. oly specified above is less than thirty (30) days, a reply ply is specified above, the maximum statutory period whin the set or extended period for reply will, by statute by the Office later than three months after the mailing an adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this commun D (35 U.S.C. § 133).	lication.		
Status						
1) Respons	ive to communication(s) filed on <u>01 M</u>	larch 2004.	•			
2a) ☐ This action	This action is FINAL . 2b) This action is non-final.					
	s application is in condition for allowar	-		its is		
closed in	accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	53 O.G. 213.			
Disposition of Cla	nims					
4) Claim(s)	1-34 is/are pending in the application.	,				
	e above claim(s) is/are withdray					
5) Claim(s)	is/are allowed.					
6) Claim(s)	<u>1-13 and 15-34</u> is/are rejected.					
7)⊠ Claim(s)	<u>14</u> is/are objected to.					
8) Claim(s)	are subject to restriction and/o	r election requirement.				
Application Paper	"S	- 	*			
9)∐ The speci	ification is objected to by the Examine	r.				
	ing(s) filed on is/are: a)☐ acc		Examiner.	4		
Applicant	may not request that any objection to the	drawing(s) be held in abeyance. See	∋ 37 CFR 1.85(a).	•		
Replacem	ent drawing sheet(s) including the correct	ion is required if the drawing(s) is ob	jected to. See 37 CFR 1.1	121(d).		
11)∐ The oath	or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-15	52.		
Priority under 35	U.S.C. § 119					
12)⊠ Acknowle	dgment is made of a claim for foreign ☐ Some * c)☐ None of:	priority under 35 U.S.C. § 119(a)	n-(d) or (f).	•		
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1) Notice of Referen		4) Interview Summary Paper No(s)/Mail Da				
	erson's Patent Drawing Review (PTO-948) osure Statement(s) (PTO-1449 or PTO/SB/08) Date		atent Application (PTO-152)			
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DETAILED ACTION

Response to Arguments

Applicant's arguments filed March 1, 2004 have been fully considered but they are not persuasive.

Regarding applicant's arguments on page 11 pertaining to the 35 USC 112 rejection of claim 24, where applicant's discuss the recited "single peak spatial mode" as being well known in the art, therefore the rejection of claim 24 is withdrawn.

Regarding applicant's arguments on pages 12 and 13 pertaining to the 35 USC 102 (b) rejection of claims 1,3,7,18-24,29-31, where discusses impermissible combination of different embodiments within the cited reference of Yamamoto et al are persuasive, therefore the rejection of claims 1,3,7,18-24,29-31 are withdrawn.

However, applicant's arguments on page 13 pertaining to the "bulk-type polarization inversion device" as not being taught or suggested by Yamamoto et al for use within other embodiment is incorrect. Applicant's attention is directed to all embodiments where the reference number for the wavelength-converting device is (22) and in column 14 lines 15-18 suggest the use of the bulk-type polarization inversion device as the light wavelength-converting device.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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Claims 1,3,10-13,15,18,19,21-32,34 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al (PN 5,452,312) in view of Sonoda (JP10254001).

Regarding claims 1,3,30,

Figure 9 illustrates a second harmonic generating laser device having a semiconductor laser (21) emitting a fundamental wave (P1), an optical transmitting filter (50) and a light wavelength converting device (22) formed from a substrate having nonlinear optical effects, as shown the filter is located between the laser and the wavelength conversion device. The wavelength conversion device includes a mirror (61) for reflecting the fundamental wavelength, as described in the abstract and column 11 lines 5-37.

Yamamoto et al does not illustrate in figure 9 a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of figure 9 with the bulk-like wavelength conversion of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Regarding claims 10,11,12,13,

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Yamamoto et al in figure 9 illustrates a filter (50) but does not explicitly disclose the filter as a thin film narrow band-pass birefringent filter.

However, the use of narrow band-pass filters in form of thin birefringent filters for wavelength selection is well known in the art as illustrated by Sonoda in figure 11 as element (91).

Regarding claim 15,

Yamamoto et al does not illustrate in figure 9 a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19. As illustrated layers (3) form a periodic pattern.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of figure 9 with the bulk-like wavelength conversion of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) resembles a bulk grating and provides easy alignment.

Regarding claim 18,

Figure 9 of Yamamoto et al does illustrate a semiconductor laser (21) coupled with the wavelength conversion device (22).

Regarding claim 19,

Figure 9 illustrates a second harmonic generating laser device having a semiconductor laser (21) emitting a fundamental wave (P1), an optical transmitting filter

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(50) and a light wavelength converting device (22) formed from a substrate having nonlinear optical effects, as shown the filter is located between the laser and the wavelength conversion device. The wavelength conversion device includes a mirror (61) for reflecting the fundamental wavelength, as described in the abstract and column 11 lines 5-37.

Yamamoto et al does not illustrate in figure 9 a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of figure 9 with the bulk-like wavelength conversion of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Yamamoto et al in figure 9 illustrates a filter (50) but does not explicitly disclose the filter as a thin film narrow band-pass birefringent filter.

However, the use of narrow band-pass filters for wavelength selection is well known in the art as illustrated by Sonoda in figure 11 as element (91).

Regarding claim 21,

In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses a bulk-type wavelength conversion composed of LiTaO₃.

Regarding claim 22,29,31,32,

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In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses a bulk-type wavelength conversion having polarization inversion layers (3), which extend to the end surfaces of the crystal.

Regarding claim 23,

In column 13 lines 45-68, Yamamoto et al discloses using semiconductor laser of 600 mW.

Regarding claim 24,

Applicant's arguments on page 11 describe the single-peak spatial mode, as being well known to one skilled in the art.

Regarding claims 25-27,

In figure 6 Yamamoto et al teaches of a technique to provide light modulation to laser system via the wavelength conversion crystal, as described in column 9 lines 45-55.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify the bulk-like wavelength conversion crystal of Yamamoto et al using the teachings of column 9 lines 45-55 because it would allow for light modulation of the bulk-like wavelength conversion crystal.

Regarding claim 28,

In column 1 lines 7-20, Yamamoto et al discloses using the laser device for optical information processing, which requires recording.

Therefore, it would have been obvious to use claimed wavelength conversion device within an optical information system, as suggested by Yamamoto et al.

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Regarding claim 34,

Figure 9 of Yamamoto et al does illustrate a structural arrangement for the laser beam emitted from laser (21) as converging on the incident side of the wavelength conversion crystal (22) and diverging as an output beam.

Claims 2-9,16,17,20,33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sonoda (JP10254001) in view of Yamamoto et al.

Regarding claim 2,3,4,33,

In figure 7 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15), a filter (14), a beam splitter (82) for separating the beam and a mirror (85) for reflecting the beam and lens (13) and (20) for converging the beam into the wavelength conversion crystal and receiving the emitted diverging beam. The waveguide and the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light. The band pass filter will provide wavelength selection.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of Sonoda in figure 7 with the bulk-like wavelength conversion crystal of figure 16 as suggested by

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Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Regarding claims 5,

In figure 9 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15), a filter (14) and a mirror (85) to feedback a backward emitted light to the laser in a direction different than towards the wavelength conversion crystal. The waveguide and the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light. The band pass filter will provide wavelength selection.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of Sonoda in figure 7 with the bulk-like wavelength conversion crystal of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Regarding claims 6,16,17,

In figure 24 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15), a lens (40) for collimating the beam into a fiber (23) with grating, which reflects part of the beam and selects the wavelength. The waveguide and

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the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of Sonoda in figure 7 with the bulk-like wavelength conversion crystal of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Regarding claim 7,

In figure 17 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15), a grating (92), which reflects part of the beam and selects the wavelength and a beam splitter (21). The waveguide and the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of Sonoda in figure 7 with the bulk-like wavelength conversion crystal of figure 16 as suggested by

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Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Regarding claim 8,

Sonoda does illustrate in figure 17 a beam splitter (21), but does not illustrate a light modulation device.

However, in figure 6 Yamamoto et al teaches of a technique to provide light modulation to laser system via the wavelength conversion crystal, as described in column 9 lines 45-55.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify the bulk-like wavelength conversion crystal of Yamamoto et al using the teachings of column 9 lines 45-55 because it would allow for light modulation of the bulk-like wavelength conversion crystal.

Regarding claim 9,

In figure 17 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15), a grating (92), to feedback a backward emitted light to the laser in a direction different than towards the wavelength conversion crystal and selects the wavelength. The waveguide and the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

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Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of Sonoda in figure 7 with the bulk-like wavelength conversion crystal of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

Regarding claim 20,

In figure 11 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15) and a narrow band-pass filter (91). The waveguide and the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

In figure 16 Yamamoto et al illustrates the use of bulk-like wavelength conversion device (22), as described in column 13 lines 45-68 to column 14 lines 1-19.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the second harmonic generating device of Sonoda in figure 7 with the bulk-like wavelength conversion crystal of figure 16 as suggested by Yamamoto et al, because the bulk-like crystal (22) provides easy alignment, as described in column 14 lines 15-18.

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Allowable Subject Matter

Claim 14 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

None of the cited references discloses the recited structural arrangement of providing on the surface of the reflecting member a thin film narrow band pass filter for wavelength selection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Armando Rodriguez whose telephone number is 571-272-1952. The examiner can normally be reached on flex / M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Don Wong can be reached on 571-272-1834. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Don Wong

Supervisor

Art Unit 2828

Armando Rodriguez Examiner Art Unit 2828

AR/DW